

**GENERAL  
INSTRUMENT**

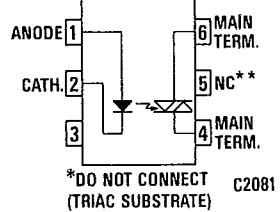
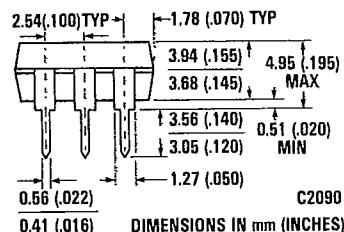
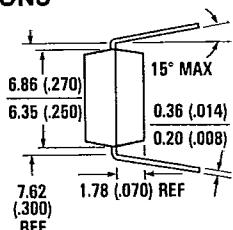
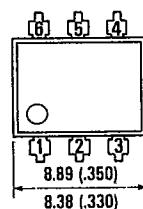


## VDE APPROVED NON-ZERO-CROSSING TRIACS

**30 mA MCP3020/0Z\***  
**NON-ZERO-CROSING 15 mA MCP3021/1Z**  
**10 mA MCP3022/2Z**

Optocouplers

### PACKAGE DIMENSIONS



C2081

Equivalent Circuit

### ABSOLUTE MAXIMUM RATINGS

#### TOTAL PACKAGE

Storage temperature	.....	-55°C to 150°C
Operating temperature	.....	-40°C to 100°C
Lead temperature (Soldering, 10 sec)	.....	260°C
Total package power dissipation @ 25°C (LED plus detector)	.....	330 mW
Derate linearly from 25°C	.....	4.0 mW/°C
Surge Isolation voltage	.....	7500 VAC Peak

### DESCRIPTION

The MCP3020, MCP3021 and MCP3022 are optically isolated triac driver devices. These devices contain a GaAs infrared emitting diode and a light activated silicon bilateral switch, which functions like a triac. This series is designed for interfacing between electronic controls and power triacs to control resistive and inductive loads for 240 VAC operations.

### FEATURES

- Minimum commuting dv/dt is specified at 0.1 V/ $\mu$ sec
- Excellent I<sub>FT</sub> stability—IR emitting diode has low degradation
- Pin for pin replacement for the MOC3020, MOC3021 and MOC3022
- High isolation voltage—minimum 7500 VAC peak
- Underwriters Laboratory (UL) recognized—File #E50151

### APPLICATIONS

- European applications for 240 VAC
- Triac driver
- Industrial controls
- Traffic lights
- Vending machines
- Motor control
- Solid state relay

\*Not Recommended  
For New Designs

### INPUT DIODE

Forward DC current	.....	60 mA
Reverse voltage	.....	3 V
Peak forward current (1 $\mu$ s pulse, 300 pps)	.....	3.0 A
Power dissipation 25°C ambient	.....	100 mW
Derate linearly from 25°C	.....	1.33 mW/°C

### OUTPUT DRIVER

Off-State Output Terminal Voltage	.....	400 Volts
On-State RMS Current	$T_A = 25^\circ\text{C}$	100 mA
	$(\text{Full Cycle, 50 to } 60 \text{ Hz})$	$T_A = 70^\circ\text{C}$
Peak Nonrepetitive Surge Current	.....	1.2 A
(PW = 10 ms, DC = 10%)		
Total Power Dissipation @ $T_A = 25^\circ\text{C}$	.....	300 mW
Derate above 25°C	.....	4.0 mW/°C

**MCP3020/0Z MCP3021/1Z MCP3022/2Z**

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**ELECTRO-OPTICAL CHARACTERISTICS (25°C Temperature Unless Otherwise Specified)**

	TRANSFER CHARACTERISTICS						
	CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
DC	LED Trigger Current (Current Required to latch output)	I <sub>FT</sub>	—	15	30	mA	Main terminal voltage = 3.0 V
	MCP3020		—	8	15		
	MCP3021		—	5	10		
dv/dt RATING	Holding Current	I <sub>H</sub>	—	200	—	μA	Either direction
	Critical Rate of Rise of Off-State Voltage	dv/dt	—	15	—	V/μs	Static dv/dt, T <sub>A</sub> = 85°C (see Figure 4)
	Critical Rate of Rise of Commutating Voltage	dv/dt	0.1	0.2	—	V/μs	Commutating dv/dt I <sub>LOAD</sub> = 15 mA (see Figure 5)
ISOLATION	Isolation Voltage	V <sub>iso</sub>	5300			V <sub>ACRMS</sub>	Relative humidity < 50%, I <sub>I-O</sub> < 10 μA, 5 seconds
		V <sub>iso</sub>	7500			V <sub>ACPKEAK</sub>	Relative humidity < 50%, I <sub>I-O</sub> < 10 μA, 5 seconds
	Isolation resistance	R <sub>iso</sub>	10 <sup>11</sup>			ohms	V <sub>I-O</sub> = 500 VDC
	Isolation capacitance	C <sub>iso</sub>		0.5		pF	f = 1 MHz

	INDIVIDUAL COMPONENT CHARACTERISTICS						
	CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
INPUT DIODE	Forward voltage	V <sub>F</sub>		1.3	1.50	V	I <sub>F</sub> = 30 mA
	Forward voltage temp. coefficient			-1.8		mV/°C	
	Reverse breakdown voltage	BV <sub>R</sub>	3.0	25		V	I <sub>R</sub> = 10 μA
	Junction capacitance	C <sub>J</sub>		50		pF	V <sub>F</sub> = 0 V, f = 1 MHz
				65		pF	V <sub>F</sub> = 1 V, f = 1 MHz
OUTPUT DETECTOR	Reverse leakage current	I <sub>R</sub>		.35	10	μA	V <sub>R</sub> = 3.0 V
	Peak Blocking Current, Either Direction	I <sub>DRM</sub>	—	10	100	nA	V <sub>DRM</sub> = 400 V, Note 1
	Peak On-State Voltage, Either Direction	V <sub>TM</sub>	—	2.0	3.0	Volts	I <sub>TM</sub> = 100 mA Peak

Note 1. Test voltage must be applied within dv/dt rating.

TYPICAL ELECTRICAL CHARACTERISTIC CURVES (25°C Free Air Temperature Unless Otherwise Specified)

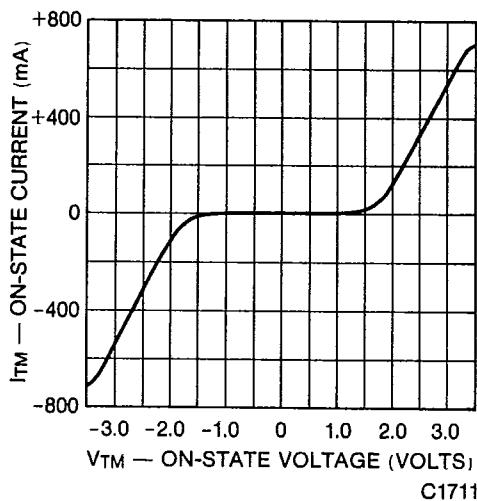


Fig. 1 On-State Characteristics

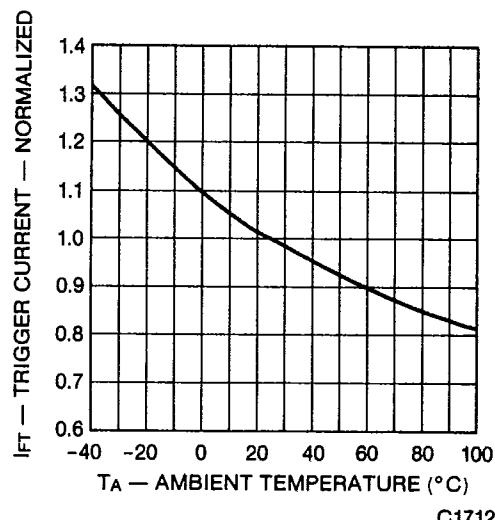
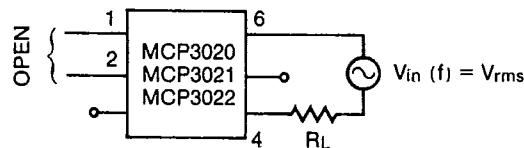
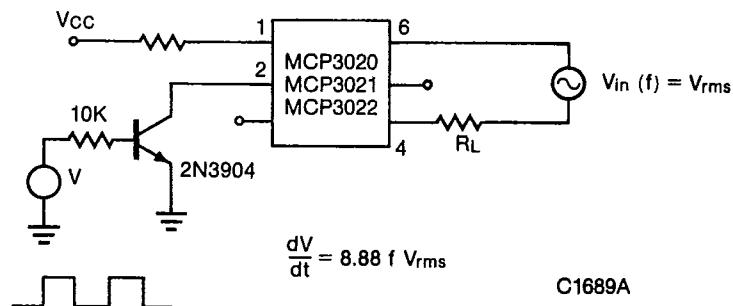


Fig. 2 Trigger Current vs. Temperature

TEST CIRCUITS FOR  $dV/dt$  MEASUREMENTS

$$\begin{aligned} \frac{dV}{dt} &= wV_{pack} = 2\pi f \times 1.414 V_{rms} \\ &= 8.88 f V_{rms} \end{aligned}$$

Fig. 3. Static  $dV/dt$ 

$$\frac{dV}{dt} = 8.88 f V_{rms}$$

C1689A

Fig. 4. Commutating  $dV/dt$